

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

Kirk D. Prall, et al.

Serial No:

Filed: February 14, 2000

For: RANDOM ACCESS MEMORY

) Attorney

) Docket Number: MICR131.02

) Group Art Unit:

) Examiner:

February 14, 2000

Assistant Commissioner of Patents
Washington, DC 20231

Sir:

PRELIMINARY AMENDMENT

Please amend the Application as follows.

In The Specification

Change the title to read -RANDOM ACCESS MEMORY--

--Cross Reference to Related Applications

This is a division of Application Serial No. 08/868,058 filed June 3, 1997,
which is a continuation of Application Serial No. 08/399,843 filed March 7, 1995.

In The Claims

Please cancel all of the existing Claims 1-22 and add the following new
claims. These new claims are identical to Claims 32-38 which were canceled in the
parent case as being drawn to a non-elected invention.

23.(new) A semiconductor memory device, comprising:

a silicon structure having a first conductivity type;

a gate electrode over the silicon structure;

a capacitor contact region in the silicon structure adjacent to one side of the
gate electrode;

MICR131.02

PRELIMINARY AMENDMENT -- 1

Stevenson
6211007
5650349

new US Pat.
6211007
new US Pat
5650349

08/868,058

91